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SLLS159F - MARCH 1993-REVISED NOVEMBER 2009

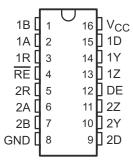
DUAL DIFFERENTIAL DRIVERS AND RECEIVERS

Check for Samples: SN65C1167 SN75C1167 SN65C1168 SN75C1168

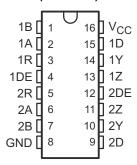
FEATURES

- Meet or Exceed Standards TIA/EIA-422-B and ITU Recommendation V.11
- BiCMOS Process Technology
- Low Supply-Current Requirements: 9 mA Max
- Low Pulse Skew
- Receiver Input Impedance . . . 17 kΩ Typ
- Receiver Input Sensitivity . . . ±200 mV
- Receiver Common-Mode Input Voltage Range of -7 V to 7 V
- Operate From Single 5-V Power Supply
- Glitch-Free Power-Up/Power-Down Protection
- Receiver 3-State Outputs Active-Low Enable for SN65C1167 and SN75C1167 Only
- Improved Replacements for the MC34050 and MC34051

SN65C1167 ... DB OR NS PACKAGE SN75C1167 ... DB, N, OR NS PACKAGE (TOP VIEW)



SN65C1168 . . . N, NS, OR PW PACKAGE SN75C1168 . . . DB, N, NS, OR PW PACKAGE (TOP VIEW)



DESCRIPTION

The SN65C1167, SN75C1167, SN65C1168, and SN75C1168 dual drivers and receivers are integrated circuits designed for balanced transmission lines. The devices meet TIA/EIA-422-B and ITU recommendation V.11.

The SN65C1167 and SN75C1167 combine dual 3-state differential line drivers and 3-state differential line receivers, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can be connected together externally to function as direction control. The SN65C1168 and SN75C1168 drivers have individual active-high enables.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

T _A	PACKAG	E ⁽¹⁾ (2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	PDIP – N	Tube	SN75C1167N	SN75C1167N	
	PDIP - N	Tube	SN75C1168N	SN75C1168N	
0°C to 70°C	SOP – NS	Tana and real	SN75C1167NSR	75C1167	
	30P - N3	Tape and reel	SN75C1168NSR	75C1168	
	SSOP – DB	Tana and real	SN75C1167DBR	CA1167	
	330P - DB	Tape and reel	SN75C1168DBR	CA1168	
	TCCOD DW	Tube	SN75C1168PW	CA1168	
	TSSOP – PW	Tape and reel	SN75C1168PWR	CATIOO	
	PDIP – N	Tube	SN65C1168N	SN65C1168N	
	SOP - NS	Tana and real	SN65C1167NSR	65C1167	
40°C to 05°C	30P - N3	Tape and reel	SN65C1168NSR	65C1168	
–40°C to 85°C	SSOP - DB	Tape and reel	SN65C1167DBR	CB1167	
	TCCOD DW	Tube	SN65C1168PW	004400	
	TSSOP – PW	Tape and reel	SN65C1168PWR	- CB1168	

⁽¹⁾ Package drawings, thermal data, and symbolization are available at www.ti.com/sc/packaging.

⁽²⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



FUNCTION TABLES

Each Driver(1)

INPUT	ENABLE	OUTI	PUTS
D	DE	Υ	Z
Н	Н	Н	L
L	Н	L	Н
X	L	Z	Z

H = high level, L = low level, X = irrelevant, Z = high impedance

Each Receiver⁽¹⁾

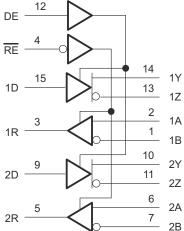
DIFFERENTIAL INPUTS A - B	ENABLE RE	OUTPUT R
V _{ID} ≥ 0.2 V	L	Н
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	L	?
V _{ID} ≤ −0.2 V	L	L
X	Н	Z
Open	L	Н

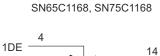
(1) H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

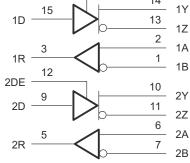
LOGIC DIAGRAM (POSITIVE LOGIC)

SN65C1167/SN75C1167

12

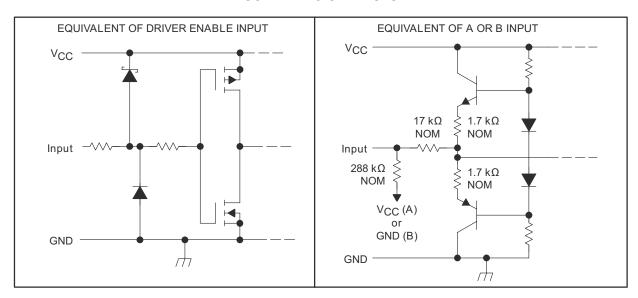




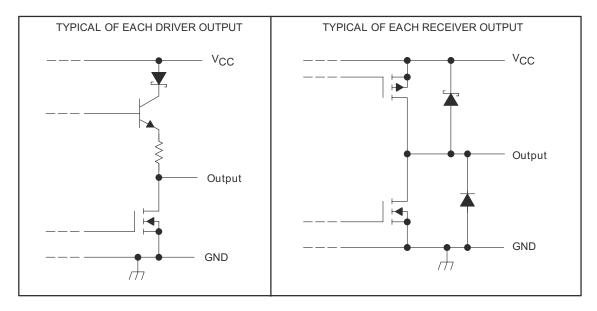




SCHEMATIC OF INPUTS



SCHEMATIC OF OUTPUTS





ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range (2)		-0.5	7	V	
\/	lanut valtage range	Driver	-0.5	V _{CC} + 0.5	V	
V _I	Input voltage range	A or B, Receiver	-11	14	V	
V_{ID}	Differential input voltage range (3)	Receiver	-14	14	V	
Vo	Output voltage range	Driver	-0.5	7	V	
I _{IK} or I _{OK}	Clamp current range	Driver		±20	mA	
I _O	Output ourrent range	Driver		±150	mA	
	Output current range	Receiver		±25		
I _{CC}	Supply current			200	mA	
	GND current			-200	mA	
T _J	Operating virtual junction temperature			150	°C	
		DB package		82		
0	Decke so the real impedance (4) (5)	N package		67	°C/W	
θ_{JA}	Package thermal impedance (4) (5)	NS package		64		
		PW package		108		
T _{stg}	Storage temperature range	-65	150	°C		

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) All voltages values except differential input voltage are with respect to the network GND.
- (3) Differential input voltage is measured at the noninverting terminal with respect to the inverting terminal.
- (4) Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_J(max) T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (5) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

				MIN	NOM	MAX	UNIT	
V _{CC}	Supply voltage			4.5	5	5.5	V	
V_{IC}	Common-mode input voltage ⁽¹⁾	Receiver			±7	V		
V_{ID}	Differential input voltage	Receiver			±7	V		
V_{IH}	High-level input voltage	Except A, B					V	
V _{IL}	Low-level input voltage	Except A, B			0.8	V		
	High lovel output ourrent	Receiver				-6	mA	
I _{OH}	High-level output current	Driver				-20	шА	
	Lavidaval avitavit avinaat	Receiver				6	A	
I _{OL}	Low-level output current	Driver				20	mA	
_			SN75C1167, SN75C1168	0		70	°C	
T_A	Operating free-air temperature		SN65C1167, SN65C1168			85		

(1) Refer to TIA/EIA-422-B for exact conditions.



DRIVER SECTION

Electrical Characteristics (1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TE	ST CONDIT	TONS	MIN	TYP ⁽²⁾	MAX	UNIT
V _{IK}	Input clamp voltage	I _I = −18 mA					-1.5	V
V _{OH}	High-level output voltage	V _{IH} = 2 V,	V _{IL} = 0.8 V,	I _{OH} = −20 mA	2.4	3.4		V
V _{OL}	Low-level output voltage	V _{IH} = 2 V,	V _{IL} = 0.8 V,	I _{OL} = 20 mA		0.2	0.4	V
V _{OD1}	Differential output voltage	$I_O = 0 \text{ mA}$			2		6	V
V _{OD2}	Differential output voltage (1)			2	3.1		V	
$\Delta V_{OD} $	Change in magnitude of differential output voltage	D 400 O 6	Dan Finne 4			±0.4	V	
V _{OC}	Common-mode output voltage	$R_L = 100 \Omega, S$	see Figure 1			±3	V	
Δ V _{OC}	Change in magnitude of common-mode output voltage						±0.4	V
	Outside several with a several "	V 0.V	V _O = 6 V				100	
I _{O(OFF)}	Output current with power off	$V_{CC} = 0 \text{ V}$ $V_{O} = -0.25 \text{ V}$					-100	μA
	High impedance state output ourrent	V _O = 2.5 V					20	
I _{OZ}	High-impedance-state output current	V _O = 5 V					-20	μΑ
I _{IH}	High-level input current	$V_I = V_{CC}$ or V	İH				1	μΑ
I _{IL}	Low-level input current	V _I = GND or \	V _{IL}				-1	μΑ
Ios	Short-circuit output current ⁽³⁾	$V_O = V_{CC}$ or C	GND,		-30		-150	mA
	Supply surrent (total pookego) (4)	No load,	V _I = V _{CC} o	r GND		4	6	mA
I _{CC}	Supply current (total package) (4)	Enabled	$V_1 = 2.4 \text{ or}$	0.5 V		5	3	IIIA
Ci	Input capacitance				6		рF	

- Refer to TIA/EIA-422-B for exact conditions.
- All typical values are at $V_{CC} = 5 \text{ V}$, and $T_A = 25^{\circ}\text{C}$. Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.
- This parameter is measured per input, while the other inputs are at V_{CC} or GND.

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST COND	OITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PHL}	Propagation delay time, high- to low-level output	R1 = R2 = 50 Ω , C1 = C2 = C3 = 40 pF,	R3 = 500Ω , S1 is open,		7	12	ns
t _{PLH}	Propagation delay time, low- to high-level output	See Figure 2			7	12	ns
t _{sk(p)}	Pulse skew				0.5	4	ns
t _r	Rise time	$R1 = R2 = 50 \Omega$,	R3 = 500 Ω,		5	10	ns
t _f	Fall time	C1 = C2 = C3 = 40 pF, SeeFigure 3	S1 is open,		5	10	ns
t _{PZH}	Output enable time to high level	$R1 = R2 = 50 \Omega$,	R3 = 500Ω ,		10	19	ns
t _{PZL}	Output enable time to low level	C1 = C2 = C3 = 40 pF, See Figure 4	S1 is closed,		10	19	ns
t _{PHZ}	Output disable time from low level	$R1 = R2 = 50 \Omega$,	R3 = 500Ω ,		7	16	ns
t _{PLZ}	Output disable time from high level	C1 = C2 = C3 = 40 pF, See Figure 4	S1 is closed,		7	16	ns

(1) All typical values are at $V_{CC} = 5 \text{ V}$, and $T_A = 25^{\circ}\text{C}$.



RECEIVER SECTION

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER		TEST (CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT+}	Positive-going input threshold volt input	age, differential					0.2	V
V _{IT}	Negative-going input threshold vo input	ltage, differential			-0.2 ⁽²⁾			V
V _{hys}	Input hysteresis (V _{IT+} - V _{IT-})					60		mV
V_{IK}	Input clamp voltage, RE	SN75C1167	I _I = −18 mA				-1.5	V
V _{OH}	High-level output voltage		$V_{ID} = 200 \text{ mV},$	I _{OH} = −6 mA	3.8	4.2		V
V _{OL}	Low-level output voltage		V _{ID} = −200 mV,	I _{OL} = 6 mA		0.1	0.3	V
l _{OZ}	High-impedance-state output current	SN75C1167	VO = VCC or GND			±0.5	±5	μΑ
I	Line input current		Other input at 0 V	V _I = 10 V V _I = -10 V			1.5 -2.5	mA
I _I	Enable input current, RE	SN75C1167	$V_I = V_{CC}$ or GND	1			±1	μΑ
ri	Input resistance		$V_{IC} = -7 \text{ V to } 7 \text{ V},$	Other input at 0 V	4	17		kΩ
	Complete compare (Astal as also as)	No lood Engblod	$V_I = V_{CC}$ or GND		4	6	A	
I _{CC}	Supply current (total package)		No load, Enabled	V _{IH} = 2.4 V or 0.5 V ⁽³⁾		5	9	mA

Switching Characteristics

over operating free-air temperature range (unless otherwise noted) (1)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	Soo Figure F	9	17	27	ns
t _{PHL}	Propagation delay time, high- to low-level output	See Figure 5	9	17	27	ns
t _{TLH}	Transition time, low- to high-level output	V - 0 V Soo Figure F		4	9	ns
t _{THL}	Transition time, high- to low-level output	V _{IC} = 0 V, See Figure 5		4	9	ns
t _{PZH}	Output enable time to high level			13	22	ns
t _{PZL}	Output enable time to low level	R _I = 1 kW, See Figure 6		13	22	ns
t _{PHZ}	Output disable time from high level	INL = 1 KW, See Figure 6		13	22	ns
t _{PLZ}	Output disable time from low level			13	22	ns

⁽¹⁾ Measured per input while the other inputs are at V_{CC} or GND (2) All typical values are at V_{CC} = 5 V and T_A = 25°C.

All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$. The algebraic convention, where the less positive (more negative) limit is designated as minimum, is used in this data sheet for common-mode input voltage and threshold voltage levels only.

Refer to TIA/EIA-422-B for exact conditions.



PARAMETER MEASUREMENT INFORMATION

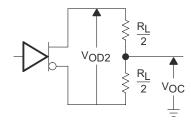


Figure 1. Driver Test Circuit, VoD and Voc

- A. C1, C2, and C3 include probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, 50% duty cycle, $t_r = t_f \le 6$ ns.

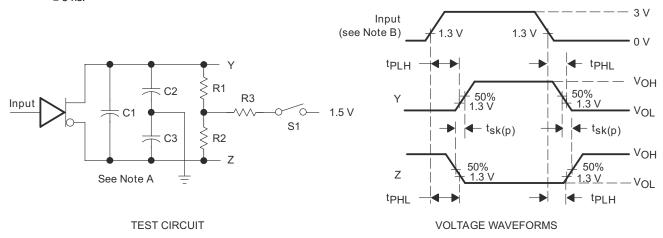


Figure 2. Driver Test Circuit and Voltage Waveforms

- C. C1, C2, and C3 include probe and jig capacitance.
- D. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, 50% duty cycle, t_r = t_f ≤ 6 ns.

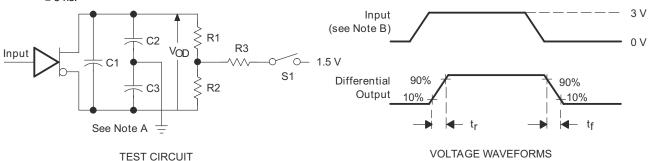


Figure 3. Driver Test Circuit and Voltage Waveforms

- E. C1, C2, and C3 include probe and jig capacitance.
- F. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, 50% duty cycle, t_r = t_f ≤ 6 ns.



PARAMETER MEASUREMENT INFORMATION (continued)

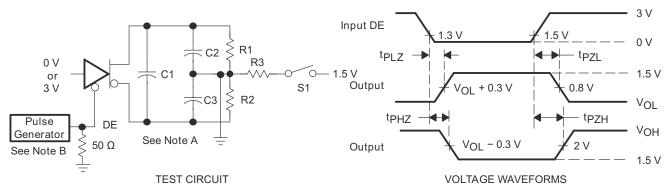


Figure 4. Driver Test Circuit and Voltage Waveforms

- G. C_L includes probe and jig capacitance.
- H. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, 50% duty cycle, $t_r = t_f \le 6$ ns.

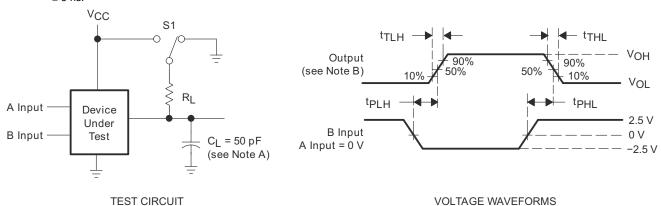


Figure 5. Receiver Test Circuit and Voltage Waveforms

- I. C_L includes probe and jig capacitance.
- J. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, 50% duty cycle, $t_r = t_f \le 6$ ns.

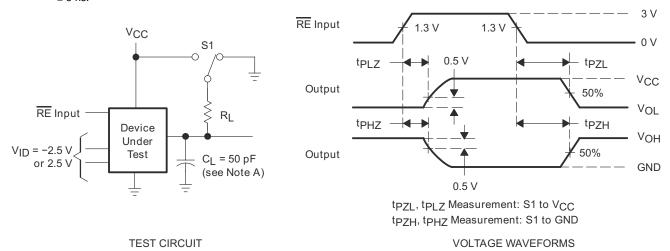


Figure 6. Receiver Test Circuit and Voltage Waveforms





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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN65C1167NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C1167	Samples
SN65C1167NSRG4	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C1167	Samples
SN65C1168N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN65C1168N	Samples
SN65C1168NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C1168	Samples
SN65C1168PW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB1168	Samples
SN65C1168PWG4	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB1168	Samples
SN65C1168PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB1168	Samples
SN75C1167DB	ACTIVE	SSOP	DB	16	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		CA1167	Samples
SN75C1167DBR	ACTIVE	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CA1167	Samples
SN75C1167N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75C1167N	Samples
SN75C1167NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75C1167	Samples
SN75C1167NSRG4	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75C1167	Samples
SN75C1168DBR	ACTIVE	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CA1168	Samples
SN75C1168N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75C1168N	Samples
SN75C1168NE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75C1168N	Samples
SN75C1168NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75C1168	Samples
SN75C1168NSRG4	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75C1168	Samples
SN75C1168PW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CA1168	Samples
SN75C1168PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CA1168	Samples
SN75C1168PWRG4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CA1168	Samples

PACKAGE OPTION ADDENDUM

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(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

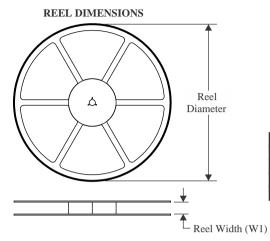
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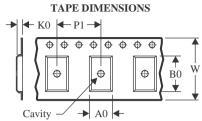
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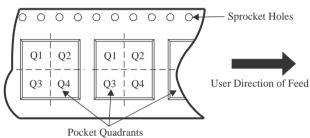
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

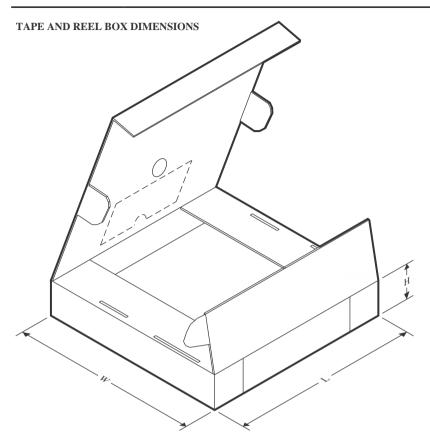


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65C1167NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN65C1168NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN65C1168PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN75C1167DBR	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN75C1167NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN75C1168DBR	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN75C1168NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN75C1168PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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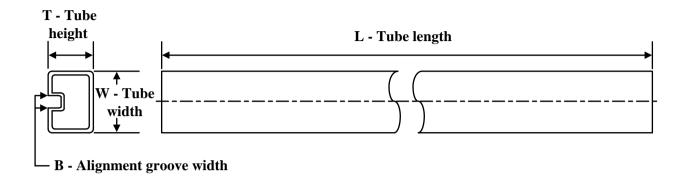
*All dimensions are nominal

Device	Package Type	Package Drawing	ng Pins SPQ Length (mm) Width (mm		Width (mm)	Height (mm)	
SN65C1167NSR	SO	NS	16	2000	356.0	356.0	35.0
SN65C1168NSR	so	NS	16	2000	356.0	356.0	35.0
SN65C1168PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN75C1167DBR	SSOP	DB	16	2000	356.0	356.0	35.0
SN75C1167NSR	so	NS	16	2000	356.0	356.0	35.0
SN75C1168DBR	SSOP	DB	16	2000	356.0	356.0	35.0
SN75C1168NSR	so	NS	16	2000	367.0	367.0	38.0
SN75C1168PWR	TSSOP	PW	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65C1168N	N	PDIP	16	25	506	13.97	11230	4.32
SN65C1168PW	PW	TSSOP	16	90	530	10.2	3600	3.5
SN65C1168PWG4	PW	TSSOP	16	90	530	10.2	3600	3.5
SN75C1167DB	DB	SSOP	16	80	530	10.5	4000	4.1
SN75C1167N	N	PDIP	16	25	506	13.97	11230	4.32
SN75C1168N	N	PDIP	16	25	506	13.97	11230	4.32
SN75C1168NE4	N	PDIP	16	25	506	13.97	11230	4.32
SN75C1168PW	PW	TSSOP	16	90	530	10.2	3600	3.5





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



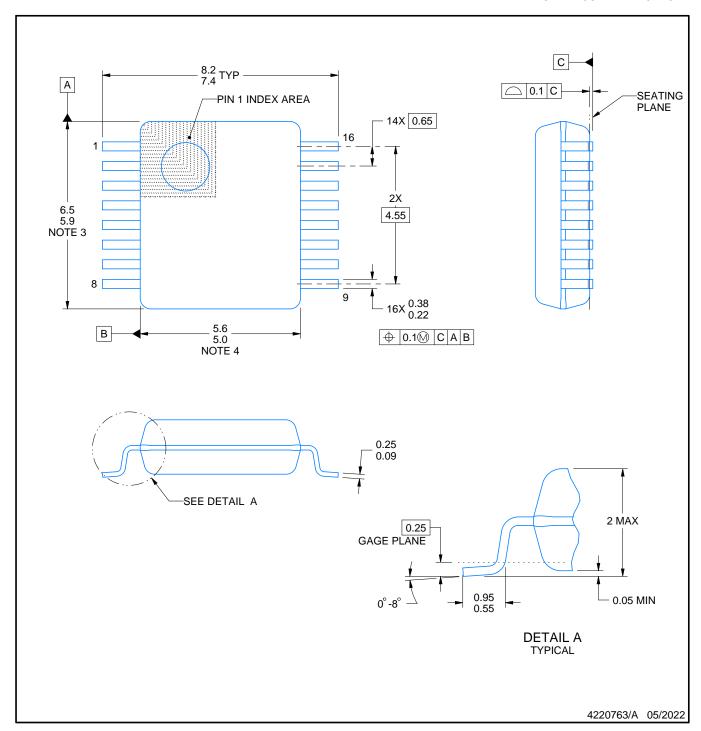


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.

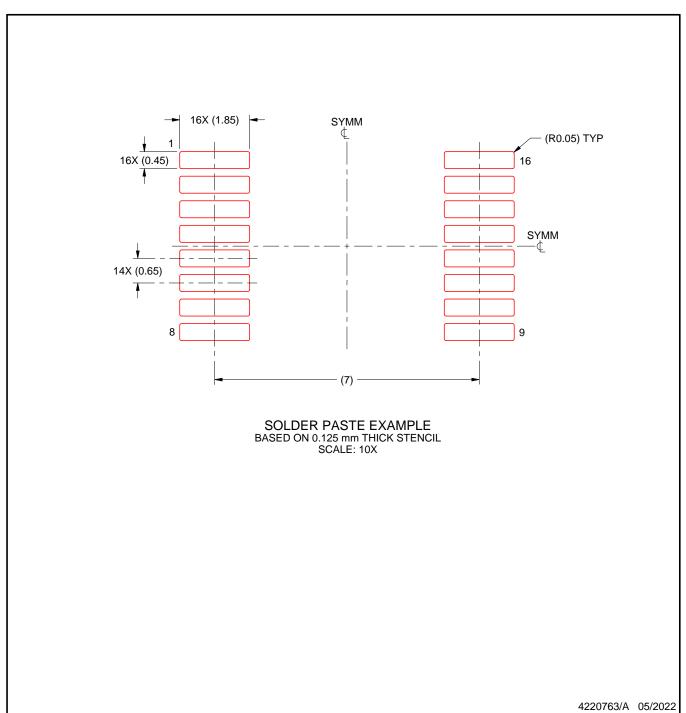




NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.

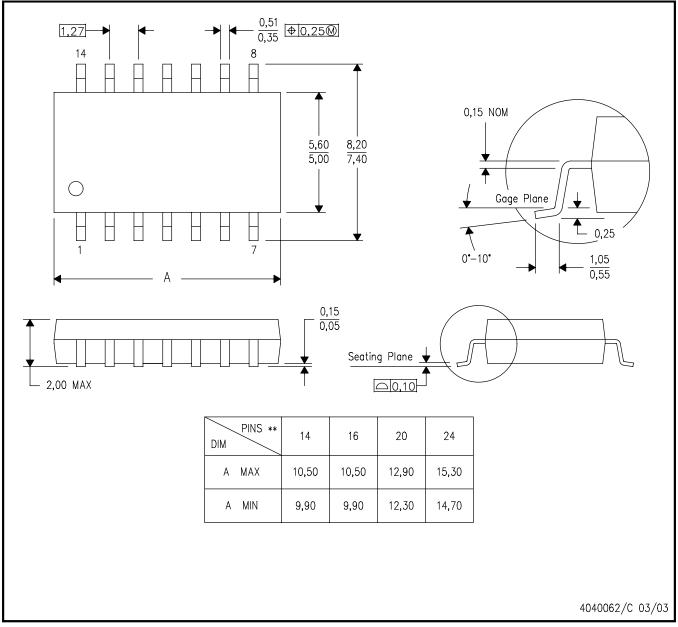


MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



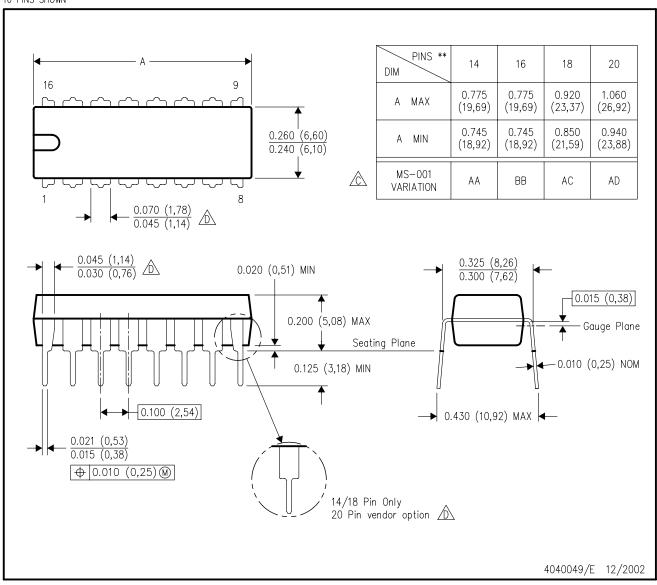
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF

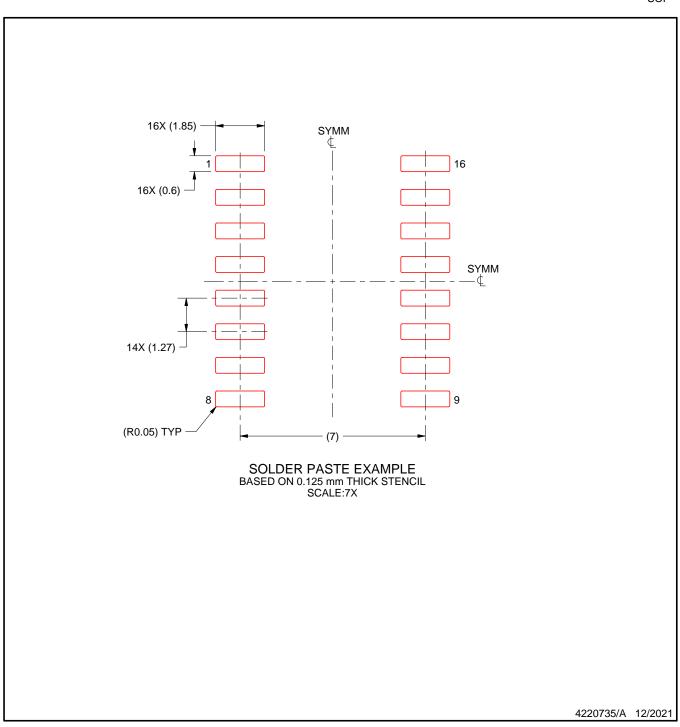


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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